PATENT

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

pplicant: Leonard Forbes et al.

Examiner:

Viet Nguyen

Serial No.: 09/135413

Group Art Unit: 2818

Filed:

August 14, 1998

Docket No:

303.354US2

Title:

METHOD FOR OPERATING A MEMORY DEVICE HAVING AN

AMORPHOUS SILICON CARBIDE GATE INSULATOR (as amended)

PRELIMINARY AMENDMENT

MS RCE Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Prior to taking up this application for examination, please enter the following amendments:

PRELIMINARY AMENDMENT Serial Number: 09/135413 Filing Date: August 14, 1998 Page 2 Docket No: 303.354US2

Filing Date: August 14, 1998

Title: METHOD FOR OPERATING A MEMORY DEVICE HAVING AN AMORPHOUS SILICON CARBIDE GATE INSULATOR (as amended)

IN THE TITLE

Please amend the title as follows:

METHOD FOR OPERATING A DEAPROM MEMORY DEVICE HAVING AN AMORPHOUS SILICON CARBIDE GATE INSULATOR